NSN 5961-01-040-0940

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-040-0940 **Inclosure Material:** Glass **Overall Length:** 0.300 inches **Terminal Length:** 1.000 inches **Overall Diameter:** 0.110 inches **Mounting Method:** Terminal Features Provided: Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: -15.0 reverse voltage, dc and 10.0 working peak reverse voltage, peak total value **Current Rating Per Characteristic:** 0.10 microamperes forward current, average peak and -100.00 microamperes zero-gate-voltage source current blank **Power Rating Per Characteristic:** 400.0 milliwatts small-signal input power, common-collector absolute **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius ambient air **Special Features:** 33 pg **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: